

Declaration of Identity

Hereby,

Name of Grantee: Hisense International Co.,Ltd
 Address: Floor 22, Hisense Tower, 17 Donghai Xi Road, Qingdao, 266071
 City: Qingdao,
 Country: China

declares that this equipment:

Product description: Mobile Phone
 Type designation(s): HLTE106E
 Trademark: Hisense

is different on

1.the supplier of Memory/Battery/CAM/ CTP/LCD.

Main Supply

Part Name	Model	Supplier(Brand)	Description
Camera	HG8M4510-V1.0	Shenzhen shennuoxin electronic technology co.LTD	rear CAM
Camera	HG7M4411-V1.0	Shenzhen shennuoxin electronic technology co.LTD	Front CAM
CTP	YX50B29TSBA00	Shengzhen AGS Optronics Tech(ShenZhen) , co.,	
LCD	YX498IS039	Shengzhen AGS Optronics Tech(ShenZhen) , co.,	
Battery	LIW380200A	SHENZHEN UTILITY POWER SOURCE CO.,LTD	

Secondary Supply

Part Name	Model Name	supplier	Description
Camera	BM18613	LUZHOU Chengxiangtong technology CO.,LTD	rear CAM
Camera	BM15563	LUZHOU Chengxiangtong technology CO.,LTD	Front CAM
CTP	Y129070F1-R	Dongguan Yuye Communication Technology Co.,Ltd	
LCD	Y88790	Shenzhen Digital Technology Co.,Ltd	
Battery	LIW380200A	ShenzhenAerospaceElectronicCo.,Ltd.	

2. Memory specification

Part Name	Model	Supplier(Brand)	Description
Memory	Model1:KKMFE10012M-B214 Model2:KMFE60012M-B214	SAMSUNG;	1+16 integrated memory
Memory	Model1:RS256M32LD3D1LMZ-125BT+E32GCYNB1ABE00 Model2: FL3B1001G-29+KM110SA1032GXA-AAA00WT,	Main supply:RAYSON+ SCY Second supply: FORESEE+ Kimtigo	1+32 separate memory

3. The PCB has differences in memory circuits, but the RF and power circuits are exactly the

same.And in order to distinguish between memory and market, the software version is different. The description is shown in the table below:

FCC ID	Product Name	Brand	Model	Internal model	Market model	Hardware version	Software version	Memory
2ADOB HLTE106	Moible phone	Hisense	HLTE106E	HLTE106E.30	Hisense U30	A507-MB-V3.6	Hisense_HLTE106E_30_S03_01_01_MX05	1+16 integrated memory
				HLTE106E.31			Hisense_HLTE106E_31_S03_01_01_MX00	
				HLTE106E.40	Hisense U30 32GB	A507-MB-V3.0	Hisense_HLTE106E_40_S03_01_01_MX06	1+32separate memory
				HLTE106E.41			Hisense_HLTE106E_41_S03_01_01_MX00	

Date:

2021-11-15

City:

Qingdao

Name:

Geng Ruifeng

Signature:

